

PMBFJ108; **PMBFJ109**; PMBFJ110 N-channel junction FETs

Rev. 4 — 20 September 2011

Product data sheet

Product profile

1.1 General description

Symmetrical N-channel junction FETs in a SOT23 package.

1.2 Features and benefits

- High-speed switching
- Interchangeability of drain and source connections
- Low R_{DSon} at zero gate voltage (< 8 Ω for PMBFJ108).

1.3 Applications

- Analog switches
- Choppers and commutators
- Audio amplifiers.

Pinning information 2.

Pinning Table 1.

Pin	Description[1]	Simplified outline Symbol
1	drain	□3
2	source	
3	gate	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

^[1] Drain and source are interchangeable.



3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
PMBFJ108	-	plastic surface mounted package; 3 leads	SOT23		
PMBFJ109					
PMBFJ110					

4. Marking

Table 3. Marking

3	
Type number	Marking code ^[1]
PMBFJ108	38*
PMBFJ109	39*
PMBFJ110	40*

^{[1] * =} p: Made in Hong Kong

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage (DC)		-	±25	V
V_{GSO}	gate-source voltage		-	-25	V
V_{GDO}	gate-drain voltage		-	-25	V
I _G	forward gate current (DC)		-	50	mA
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1] -	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

^[1] Mounted on an FR4 printed-circuit board.

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>11</u> 500	K/W

^[1] Mounted on an FR4 printed-circuit board.

^{* =} t: Made in Malaysia

^{* =} W: Made in China

7. Static characteristics

Table 6. Static characteristics

 $T_j = 25 \, ^{\circ}\text{C}$.

,						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{GSS}	gate-source leakage current	$V_{GS} = -15 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	-3	nΑ
I_{DSX}	drain-source cut-off current	$V_{GS} = -10 \text{ V}; V_{DS} = 5 \text{ V}$	-	-	3	nΑ
I_{DSS}	drain-source leakage current					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}$	80	-	-	mΑ
	PMBFJ109	V _{GS} = 0 V; V _{DS} = 15 V	40	-	-	mΑ
	PMBFJ110	V _{GS} = 0 V; V _{DS} = 15 V	10	-	-	mΑ
$V_{(BR)GSS}$	gate-source breakdown voltage	$I_G = -1 \mu A; V_{DS} = 0 V$	-	-	-25	V
V_{GSoff}	gate-source cut-off voltage					
	PMBFJ108	$I_D = 1 \mu A; V_{DS} = 5 V$	-10	-	-3	V
	PMBFJ109	$I_D = 1 \mu A; V_{DS} = 5 V$	-6	-	-2	V
	PMBFJ110	$I_D = 1 \mu A; V_{DS} = 5 V$	-4	-	-0.5	V
R_{DSon}	drain-source on-state resistance					
	PMBFJ108	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	8	Ω
	PMBFJ109	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	12	Ω
	PMBFJ110	$V_{GS} = 0 \text{ V}; V_{DS} = 0.1 \text{ V}$	-	-	18	Ω

8. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C_{iss}	input capacitance	$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$		-	15	30	pF
		$V_{DS} = 0 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$		-	50	85	pF
C _{rss}	feedback capacitance	$V_{DS} = 0 \text{ V}; V_{GS} = -10 \text{ V}; f = 1 \text{ MHz}$		-	8	15	pF
Switching	g times (see <u>Figure 2</u>)						
t _d	delay time		<u>[1]</u>	-	2	-	ns
t _{on}	turn-on time		<u>[1]</u>	-	4	-	ns
ts	storage time		<u>[1]</u>	-	4	-	ns
t _{off}	turn-off time		[1]	-	6	-	ns

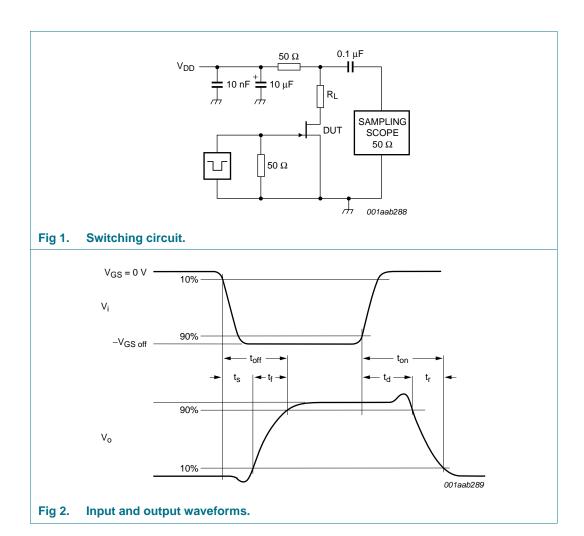
[1] Test conditions for switching times are as follows:

 V_{DD} = 1.5 V, V_{GS} = 0 V to V_{GSoff} (all types);

 $V_{GSoff} = -12 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ108)};$

 $V_{GSoff} = -7 \text{ V}, R_L = 100 \Omega \text{ (PMBFJ109)};$

 V_{GSoff} = –5 V, R_L = 100 Ω (PMBFJ110).



9. Package outline

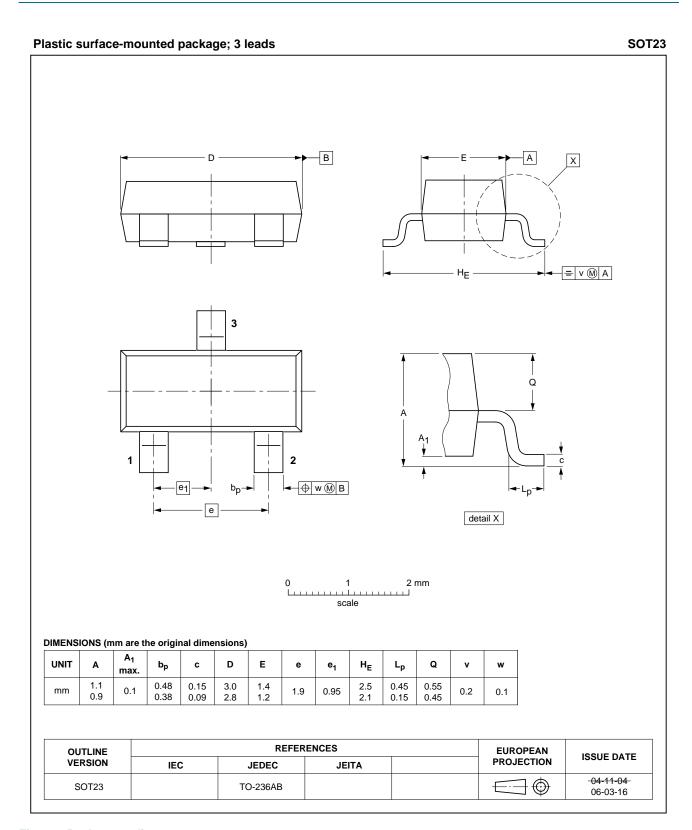


Fig 3. Package outline.

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMBFJ108_109_110 v.4	20110920	Product data sheet	-	PMBFJ108_109_110 v.3
 Modifications: The format of this data sheet has been redesigned to comply with the guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where app Package outline drawings have been updated to the latest version. 				name where appropriate.
PMBFJ108_109_110 v.3 (9397 750 13401)	20040804	Product data sheet	-	PMBFJ108_109_110_CNV v.2
PMBFJ108_109_110_CNV v.2	19971201	Product specification	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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N-channel junction FETs

13. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
2	Pinning information	1
3	Ordering information	2
4	Marking	2
5	Limiting values	2
6	Thermal characteristics	2
7	Static characteristics	3
8	Dynamic characteristics	3
9	Package outline	5
10	Revision history	6
11	Legal information	7
11.1	Data sheet status	7
11.2	Definitions	7
11.3	Disclaimers	7
11.4	Trademarks	8
12	Contact information	8
13	Contents	q

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